



Spec No.: DS30-2001-416Effective Date: 11/17/2001

Revision: -

LITE-ON DCC

RELEASE

BNS-OD-FC001/A4

LITEON

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FEATURES

- *0.3 inch (7.62 mm) DIGIT HEIGHT.
- *CONTINUOUS UNIFORM SEGMENTS.
- *LOW POWER REQUIREMENT.
- *EXCELLENT CHARACTERS APPEARANCE.
- *HIGH BRIGHTNESS & HIGH CONTRAST.
- *WIDE VIEWING ANGLE.
- * SOLID STATE RELIABILITY.
- *CATEGORIZED FOR LUMINOUS INTENSITY.

DESCRIPTION

The LTD-322JD is a 0.3 inch (7.62 mm) digit height display. This device utilizes AlInGaP Hyper Red LED chips, which are made from AlInGaP on a non-transparent GaAs substrate, and has a black face and white segments.

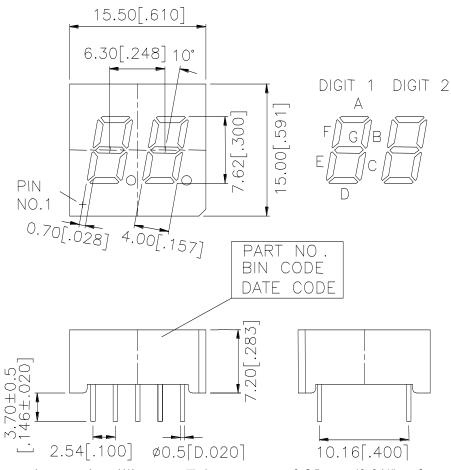
DEVICE

PART NO.	DESCRIPTION		
AlInGaP Hyper Red			
LTD-322JD	Duplex Common Cathode		

PART NO.: LTD-322JD PAGE: 1 of 5

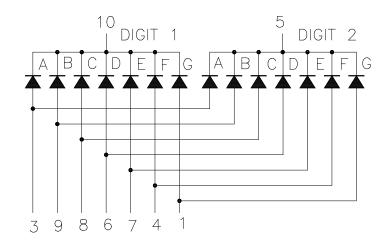
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PACKAGE DIMENSIONS



NOTES: All dimensions are in millimeters. Tolerances are ± 0.25 mm (0.01") unless otherwise noted.

INTERNAL CIRCUIT DIAGRAM



PAGE: PART NO.: LTD-322JD 2 of 5

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PIN CONNECTION

No	CONNECTION
1	ANODE G
2	NO PIN
3	ANODE A
4	ANODE F
5	COMMON CATHODE (DIGIT 2)
6	ANODE D
7	ANODE E
8	ANODE C
9	ANODE B
10	COMMON CATHODE (DIGIT 1)

PAGE: PART NO.: LTD-322JD 3 of 5



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ABSOLUTE MAXIMUM RATING AT Ta=25°C

PARAMETER	MAXIMUM RATING	UNIT			
Power Dissipation Per Segment	70	mW			
Peak Forward Current Per Segment (1/10 Duty Cycle, 0.1ms Pulse Width)	90	mA			
Continuous Forward Current Per Segment	25	mA			
Derating Linear From 25°C Per Segment	0.33	mA/°C			
Reverse Voltage Per Segment	5	V			
Operating Temperature Range	-35°C to +85°C				
Storage Temperature Range	-35°C to +85°C				
Solder Temperature: max 260°C for max 3sec at 1.6mm below seating plane.					

ELECTRICAL / OPTICAL CHARACTERISTICS AT Ta=25°C

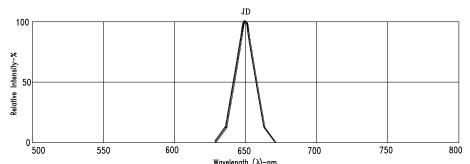
PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Average Luminous Intensity	Iv	200	600		μcd	I _F =1mA
Peak Emission Wavelength	λр		650		nm	I _F =20mA
Spectral Line Half-Width	Δλ		20		nm	I _F =20mA
Dominant Wavelength	λd		639		nm	I _F =20mA
Forward Voltage Per Segment	VF		2.1	2.6	V	I _F =20mA
Reverse Current Per Segment	Ir			100	μΑ	V _R =5V
Luminous Intensity Matching Ratio	Iv-m			2:1		I _F =1mA

Note: Luminous intensity is measured with a light sensor and filter combination that approximates the CIE (Commision Internationale De L'Eclairage) eye-response curve.

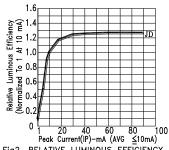
PART NO.: LTD-322JD PAGE: 4 of 5

TYPICAL ELECTRICAL / OPTICAL CHARACTERISTIC CURVES

(25°C Ambient Temperature Unless Otherwise Noted)

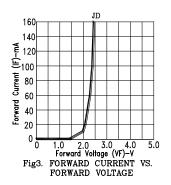


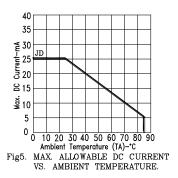
Wavelength (\(\lambda\right)\)-nm.
Fig1. RELATIVE INTENSITY VS. WAVELENGTH

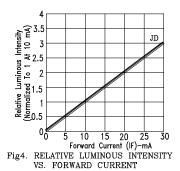


Peak Current(IP)-mA (AVG ≤10mA)

Fig2. RELATIVE LUMINOUS EFFICIENCY
(LUMINOUS INTENSITY PER UNIT
CURRENT) VS. PEAK CURRENT







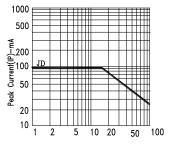


Fig6. MAX. PEAK CURRENT VS.
DUTY CYCLE %
(REFRESH RATE 1KHz)

NOTE : JD=AlInGaP HYPER RED

PART NO.: LTD-322JD PAGE: 5 of 5